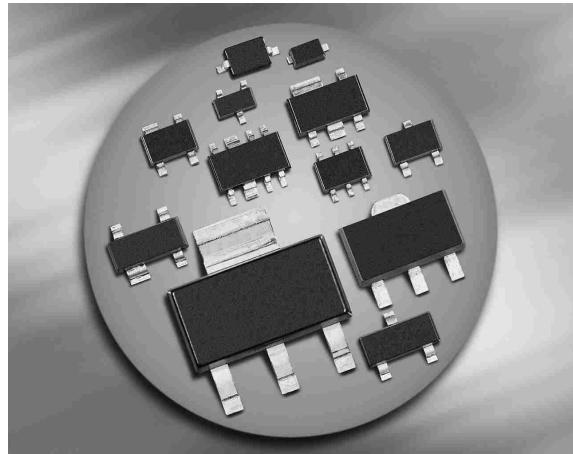
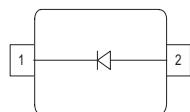


### Silicon Tuning Diodes

- Extended frequency range up to 2.5 GHz;  
spezial design for use in TV-sat tuners
- High capacitance ratio
- Pb-free (RoHS compliant) package



### BB833



Type	Package	Configuration	$L_S$ (nH)	Marking
BB833	SOD323	single	1.8	white X

**Maximum Ratings** at  $T_A = 25^\circ\text{C}$ , unless otherwise specified

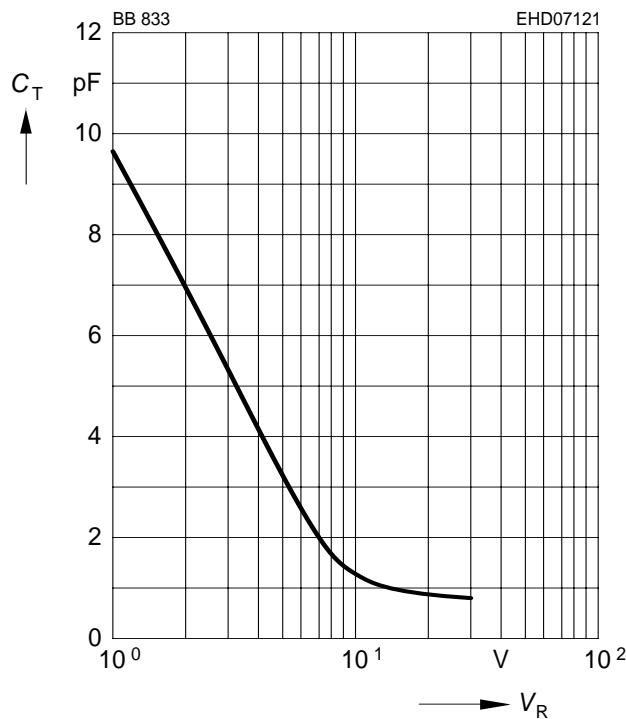
Parameter	Symbol	Value	Unit
Diode reverse voltage	$V_R$	30	V
Peak reverse voltage- $R \geq 5\text{k}\Omega$	$V_{RM}$	35	
Forward current	$I_F$	20	mA
Operating temperature range	$T_{op}$	-55 ... 150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 ... 150	

**Electrical Characteristics** at  $T_A = 25^\circ\text{C}$ , unless otherwise specified

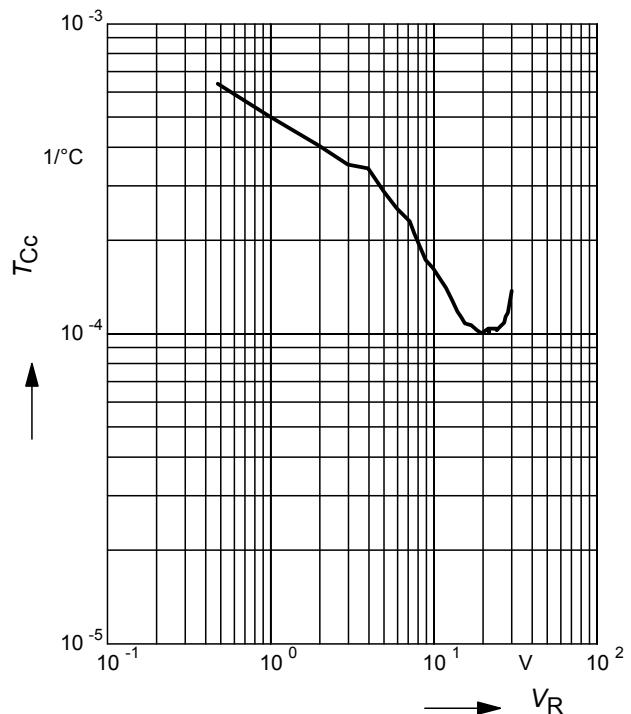
Parameter	Symbol	Values			Unit
		min.	typ.	max.	
<b>DC Characteristics</b>					
Reverse current $V_R = 30 \text{ V}$	$I_R$	-	-	20	nA
$V_R = 30 \text{ V}, T_A = 85^\circ\text{C}$		-	-	500	
<b>AC Characteristics</b>					
Diode capacitance $V_R = 1 \text{ V}, f = 1 \text{ MHz}$	$C_T$	8.5	9.3	10	pF
$V_R = 28 \text{ V}, f = 1 \text{ MHz}$		0.6	0.75	0.9	
Capacitance ratio $V_R = 1 \text{ V}, V_R = 28 \text{ V}, f = 1 \text{ MHz}$	$C_{T1}/C_{T28}$	11	12.4	-	
Capacitance matching <sup>1)</sup> $V_R = 1 \text{ V}, V_R = 28 \text{ V}, f = 1 \text{ MHz}$	$\Delta C_T/C_T$	-	-	3	%
Series resistance $V_R = 1 \text{ V}, f = 470 \text{ MHz}$	$r_S$	-	1.8	-	$\Omega$

<sup>1)</sup>For details please refer to Application Note 047.

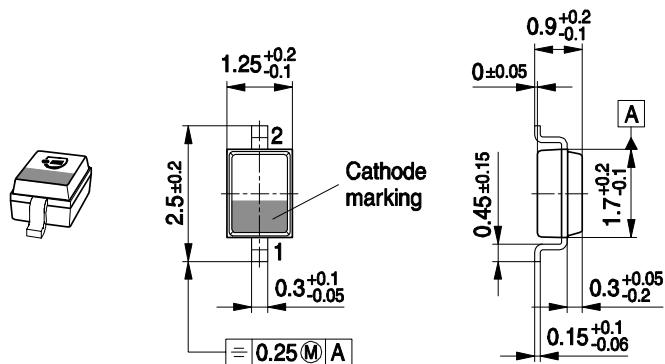
Diode capacitance  $C_T = f (V_R)$   
 $f = 1\text{MHz}$



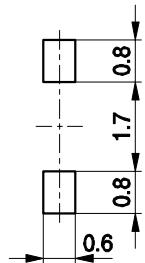
Temperature coefficient of the diode capacitance  $T_{Cc} = f (V_R)$



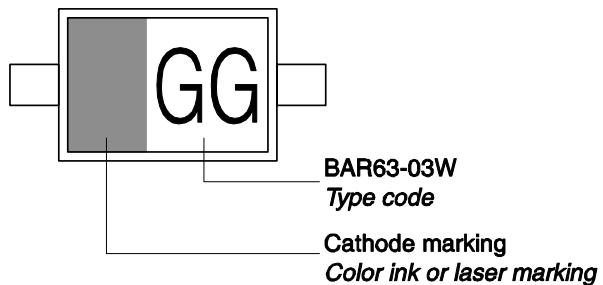
## Package Outline



## Foot Print



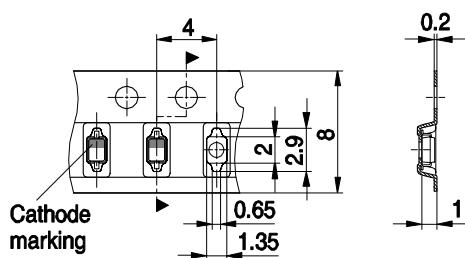
## Marking Layout (Example)



## Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel

Reel ø330 mm = 10.000 Pieces/Reel



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